

| L Number | Hits | Search Text  | DB  | Time stamp          |
|----------|------|--|---|---------------------|
| 1        | 318  | (372/68).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 2        | 467  | (385/45).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 3        | 420  | (372/66).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 4        | 911  | (385/17).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 5        | 1978 | (372/50).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 6        | 518  | (385/46).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 7        | 539  | (372/97).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:16 |
| 8        | 251  | (372/\$.ccls. 385/\$.ccls.) and ((multi adj mode multimode) adj2 interference MMI) adj (region coupler) and (wave adj guide waveguide)                       | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:17 |
| 9        | 156  | laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic) | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:17 |
| 10       | 616  | (385/28).CCLS.   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:17 |
| 11       | 323  | ((385/28).CCLS.) and laser   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:17 |
| 12       | 64   | ((385/17).CCLS.) and semiconductor adj laser   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:18 |
| 13       | 72   | ((385/28).CCLS.) and semiconductor adj laser   | USPAT;<br>US-PGPUB;<br>EPO; JPO;<br>DERWENT | 2004/08/20<br>11:18 |